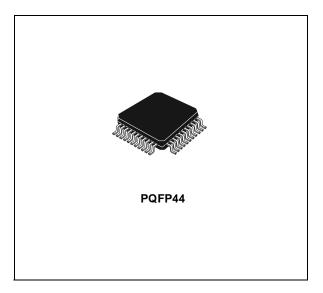




- MANY DISPLAY MODES (11 SEGMENTS & 11 DIGITS TO 16 SEGMENTS & 4 DIGITS)
- KEY SCANNING (6 x 4 MATRIX)
- DIMMING CIRCUIT (EIGHT STEPS)
- HIGH-VOLTAGE OUTPUT (V<sub>DD</sub> 35V MAX)
- LED PORTS (4 CHS, 20mA MAX)
- GENERAL PURPOSE INPUT PORT (4 bits)
- NO EXTERNAL RESISTOR NECESSARY FOR DRIVER OUTPUT (P-CH OPEN DRAIN + PULL DOWN RESISTOR OUTPUT)
- SERIAL INTERFACE (CLK, STB, D<sub>IN</sub>, D<sub>OUT</sub>)

#### DESCRIPTION

The STM86312 is a VFD (Vacuum Fluorescent Display) controller/driver that is driven on a 1/4 to 1/11-duty factor. It consists of 11-segments output lines, 6 grid output lines, 5 segments/grid output drive lines, a display memory, a control circuit, and a key scan circuit. Serial data are input to the STM86312 through a three-line serial interface.



This VFD controller/driver is ideal as a peripheral device for a single-chip microcomputer.

#### **ORDERING CODES**

Туре	Temperature Range	Package	Comments
STM86312	-40 to 85 °C	PQFP44	250 parts per Reel

## Figure 1: Block Diagram

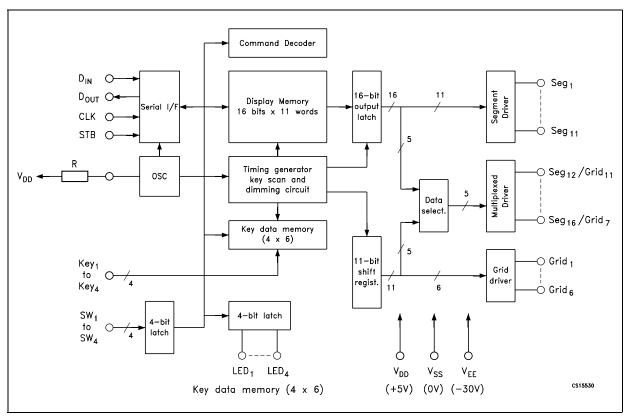
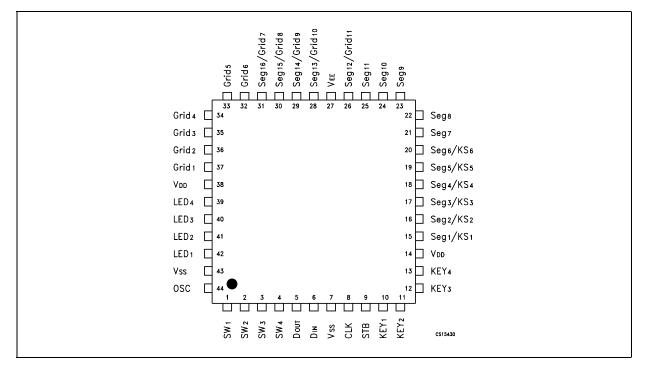


Figure 2: Pin Configuration (TOP VIEW)



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# Table 1: Pin Description

PIN N°	SYMBOL	NAME AND FUNCTION
1, 2, 3, 4	SW1, SW2, SW3, SW4	General-purpose switch inputs.
5	D <sub>OUT</sub>	Output serial data at falling edge of the shift clock, starting from lower bit. This is N-ch open-drain output pin.
6	D <sub>IN</sub>	Input serial data at rising edge of the shift clock, starting from lower bit.
8	CLK	Reads serial data at rising edge, and outputs data at falling edge.
9	STB	Initializes serial interface at rising or falling edge to make STM86312 waiting for reception of command. Data input after STB has fallen are processed as a command. While command data are processed, current processing is stopped, and the serial interface is initialized. While STB is high, CLK is ignored.
10, 11, 12, 13	KEY1, KEY2, KEY3, KEY4	Input data to these pins are latched at end of the display cycle.
14, 38	V <sub>DD</sub>	5V ± 10%.
15, 16, 17, 18, 19, 20	SEG1/KS1 to SEG6/KS6	Segment output pins (Dual function as key source).
21, 22, 23, 24, 25	SEG7 to SEG11	Segment output pins.
26, 28, 29, 30, 31	SEG12/GRID11 to SEG16/GRID7	These pins are selectable for segment or grid driving.
32, 33, 34, 35, 36, 37	GRID1 to GRID6	Grid output pins.
39, 40, 41, 42	LED1 to LED4	CMOS outputs. +20 mA max.
7, 43	V <sub>SS</sub>	Connect this pin to system GND.
27	V <sub>EE</sub>	Pull-down level. V <sub>DD</sub> - 35V max.
44	OSC	Connect to an external resistor.

# **Table 2: Absolute Maximum Ratings** ( $T_A = 25^{\circ}C$ , $V_{SS} = 0V$ )

Symbol	Parameter	Value	Unit	
V <sub>DD</sub>	Logic Supply Voltage	-0.5 to 7	V	
$V_{EE}$	Driver Supply Voltage	V <sub>DD</sub> +0.5 to V <sub>DD</sub> -40	V	
VI	Logic Input Voltage	-0.5 to V <sub>DD</sub> +0.5		
V <sub>O2</sub>	VFD Driver Output Voltage	V <sub>EE</sub> -0.5 to V <sub>DD</sub> +0.5	V	
I <sub>O1</sub>	LED Driver Output Current	25		
la.	VFD Driver Output Current	-40 (Grid)	mA	
I <sub>O2</sub>		-15 (Segment)		
T <sub>A</sub>	Operating Ambient Temperature	-40 to 85	°C	

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

## **Table 3: Thermal Data**

Symbol	Parameter	Value	Unit
R <sub>Tj-c</sub>	Thermal Resistance Junction-Case	56	°C/W

## **Table 4: Recommended Operating Conditions**

Symbol	Parameter	Min	ТҮР	Max	Unit
V <sub>DD</sub>	Logic Supply Voltage	4.5	5	5.5	V
V <sub>IH</sub>	High Level Input Voltage	0.7xV <sub>DD</sub>		V <sub>DD</sub>	V
V <sub>IL</sub>	Low Level Input Voltage	0		0.3xV <sub>DD</sub>	V
V <sub>EE</sub>	Driver Supply Voltage	0		V <sub>DD</sub> -35	V

Maximum power consumption  $P_{MAX}$  = VFD driver dissipation +  $R_L$  dissipation + LED driver dissipation + dynamic power consumption.

Where segment current = 3 mA, grid current = 15 mA, and LED current = 20 mA,

VFD driver dissipation = number of segments x 6 + number of grids/(number of grids + 1) x 30 (mW)  $R_L$  dissipation =  $(V_{DD} - V_{EE})^2/50$  x (segment + 1) (mW)

LED driver dissipation = number of LEDs x 20 (mW)

Dynamic power consumption =  $V_{DD} \times 5$  (mW)

Example

Where  $V_{EE} = -25$  V,  $V_{DD} = 5$  V, and in 16-segment and 6-digit modes, VFD driver dissipation = 16 x 6 + 6/7 x 30 = 122 R<sub>L</sub> dissipation =  $30^2/50$  x 17 = 306 LED driver dissipation = 4 x 20 = 80 Dynamic power consumption = 5 x 5 = 25 Total 553 mW.

**Table 5: Electrical Characteristics** ( $V_{DD}$  = 4.5 to 5.5V,  $V_{SS}$  = 0V,  $V_{EE}$  =  $V_{DD}$  - 35V,  $T_A$  = -20 to 70°C, unless otherwise noted. Typical values are at  $T_A$  = 25°C)

Symbol	Devenueter	Test Can ditions	Value			
	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>OH1</sub>	High Level Output Voltage	LED1-LED4, I <sub>OH1</sub> =-1mA	$0.9V_{DD}$			V
V <sub>OL1</sub>	Low Level Output Voltage	LED1-LED4, I <sub>OL1</sub> =20mA			1	V
V <sub>OL2</sub>	Low Level Output Voltage	D <sub>OUT</sub> , I <sub>OL2</sub> = 4mA			0.4	V
I <sub>OH21</sub>	High Level Output Current	$V_0 = V_{DD} - 2V$ , Seg1 to Seg11	-3			mA
I <sub>OH22</sub>	High Level Output Current	$V_O = V_{DD} - 2V$ , Grid1 to Grid6, Seg12/Grid11 to Seg16/Grid7	-15			mA
I <sub>OLEAK</sub>	Driver Leakage Current	$V_0 = V_{DD} - 35V$ , driver off			-10	μΑ
RL	Output Pull-Down Resistor	Driver Output	50	100	150	kΩ
Ц	Input Current	$V_{I} = V_{DD} \text{ or } V_{SS}$			±1	μA
V <sub>IH</sub>	High Level Input Voltage		$0.7V_{DD}$			V
V <sub>IL</sub>	Low Level Input Voltage				$0.3V_{DD}$	V
V <sub>HYS</sub>	Hysteresis Voltage	CLK, D <sub>IN</sub> , STB		0.35		V
I <sub>DDdyn</sub>	Dynamic Current Consumption	Under no load, display off			5	mA

Symbol	Parameter	Test Conditions		Value			Unit
Symbol Parameter				Min.	Тур.	Max.	Unit
t <sub>PLZ</sub>	Propagation Delay	$CLK \rightarrow D_{OUT}$				300	ns
t <sub>PZL</sub>		$R_L$ = 10 kΩ, $C_L$ = 15 pF				100	
t <sub>TZH1</sub>	Rise Time	C <sub>L</sub> = 300 pF	Seg1 to Seg11			2	μs
t <sub>TZH2</sub>			Grid1 to Grid6, Seg12/ Grid11 to Seg16/Grid7			0.5	
t <sub>THZ</sub>	Fall Time	C <sub>L</sub> = 300 pF, Segn, Gridn				120	μs
f <sub>MAX</sub>	Maximum Clock Frequency	Duty = 50%		1			MHz
CI	Input Capacitance					15	pF

**Table 6: Switching Characteristics** ( $V_{DD}$  = 4.5 to 5.5V,  $V_{SS}$  = 0V,  $V_{EE}$  =  $V_{DD}$  - 35V,  $T_A$  = -20 to 70°C, unless otherwise noted. Typical values are at  $T_A$  = 25°C)

**Table 7: Timing Characteristics** (V<sub>DD</sub> = 4.5 to 5.5V,  $T_A$  = -20 to 70°C, unless otherwise noted. Typical values are at  $T_A$  = 25°C)

Symbol	Parameter	Test Conditions	Value			Unit
	Falameter	rest conditions	Min.	Тур.	Max.	Onit
PW <sub>CLK</sub>	Clock Pulse Width		400			ns
PW <sub>STB</sub>	Strobe Pulse Width		1			μs
t <sub>SETUP</sub>	Data Setup Time		100			ns
t <sub>HOLD</sub>	Data Hold Time		100			ns
t <sub>CLK-STB</sub>	Clock-Strobe Time	$CLK \uparrow \rightarrow STB \uparrow$	1			μs
t <sub>WAIT</sub>	Wait Time (Note 1)	$CLK \uparrow \rightarrow CLK \downarrow$	1			μs

NOTE 1: Refer to page Serial Communication Format.

#### DISPLAY RAM ADDRESS AND DISPLAY MODE

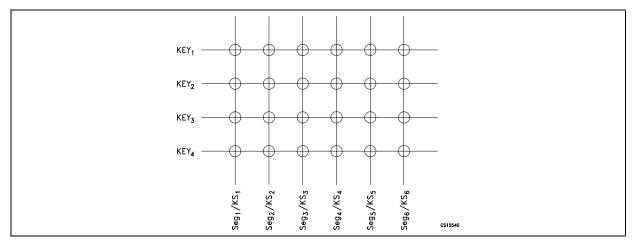
The display RAM stores the data transmitted from an external device to the STM86312 through the serial interface; addresses are as follows, in 8-bits unit:

Seg1	Seg4	Seg8	Seg12	: :	Seg16
00 H	_	00 H <sub>U</sub>	01 H <sub>L</sub>	01 H <sub>U</sub>	DIG1
02 H	_	02 H <sub>U</sub>	03 H <sub>L</sub>	03 H <sub>U</sub>	DIG2
04 H <sub>l</sub>	_	04 H <sub>U</sub>	05 H <sub>L</sub>	05 H <sub>U</sub>	DIG3
06 H	_	06 H <sub>U</sub>	07 H <sub>L</sub>	07 H <sub>U</sub>	DIG4
08 H	_	08 H <sub>U</sub>	09 H <sub>L</sub>	09 H <sub>U</sub>	DIG5
0A H	L	0A H <sub>U</sub>	0B H <sub>L</sub>	0В Н <sub>U</sub>	DIG6
0C H	L	0C H <sub>U</sub>	0D H <sub>L</sub>	0D H <sub>U</sub>	DIG7
0E H	L	0E H <sub>U</sub>	0F H <sub>L</sub>	0F H <sub>U</sub>	DIG8
10 H <sub>l</sub>	_	10 H <sub>U</sub>	11 H <sub>L</sub>	11 H <sub>U</sub>	DIG9
12 H	_	12 H <sub>U</sub>	13 H <sub>L</sub>	13 H <sub>U</sub>	DIG10
14 H	_	14 H <sub>U</sub>	15 H <sub>L</sub>	15 H <sub>U</sub>	DIG11
b0		b3 b4	ł	o7	
	XX H <sub>L</sub>		XX H <sub>U</sub>		

"0" in memory means  $V_{\mbox{\scriptsize EE}}$  on output; "1" in memory means  $V_{\mbox{\scriptsize DD}}$  on output.

## Figure 3: Key Matrix And Key-input Data Storage Ram

The key matrix is of 6 x 4 configuration, as shown below



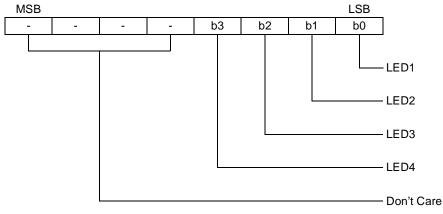
The data of each key are stored as illustrated below, and are read by the appropriate read command, starting from the least significant bit

KEY1	KE	Y4 KEY1	KEY4	
	Seg1/KS1	Seg2/KS2		
	Seg3/KS3	Seg4KS4		
	Seg5/KS5	Seg6/KS6		$\mathbf{v}$
b0		b3 b4	b7	

## LED PORT

Data are written to the LED port by a write command, starting from the least significant bit of the port. When a bit of this port is 0, the corresponding LED lights; when the bit is 1, the LED goes off. The data of bits 5 through 8 are ignored.

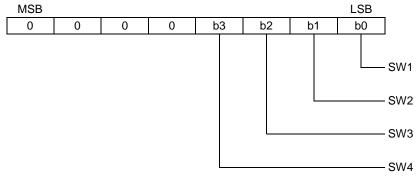
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On power application, all the LEDs remain dark.

## SW DATA

The SW data are read by the appropriate read command, starting from the least significant bit. Bits 5 through 8 of the SW data are 0.



#### COMMANDS

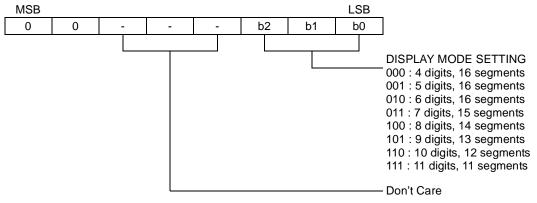
A command sets the display mode and status of the VFD driver.

The first 1 byte input to the STM86312 through the  $D_{IN}$  pin after the STB pin has fallen is regarded as a command. If STB is set high while commands/data are transmitted, serial communication is initialized, and the commands/data being transmitted are invalid (however, the commands/data already transmitted remain valid).

#### (1) DISPLAY MODE SETTING COMMAND

This command initializes the STM86312 and selects the number of segments and number of grids (1/4 to 1/11 duty, 11 segments to 16 segments).

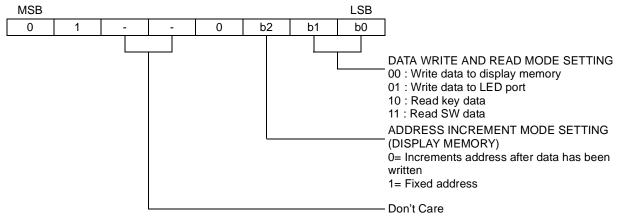
When this command is executed, display is forcibly turned off, and key scanning is also stopped. To resume display, the display ON command must be executed. If the same mode is selected, however, nothing is performed.



On power application, the 11-digit 11-segment mode is selected.

## (2) DATA SETTING COMMAND

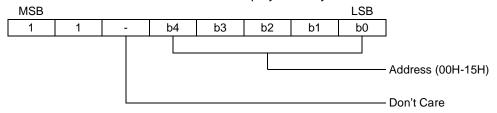
This command sets data write and data read modes.



On power application, the normal operation mode and address increment mode are set. Do not use STM86312 in test mode.

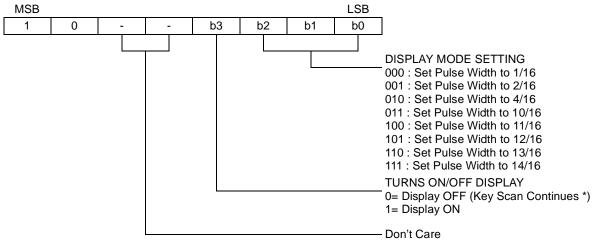
### (3) ADDRESS SETTING COMMAND

This command sets an address of the display memory



If address 16H or higher is set, the data are ignored, until a correct address is set. On power application, the address is set to 00H.





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On power application, the 1/16-pulse width is set and the display is turned off. \*: On power application, key scanning is stopped.

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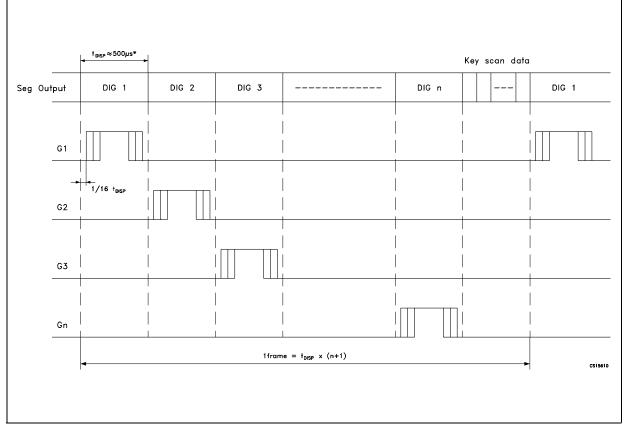
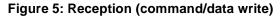
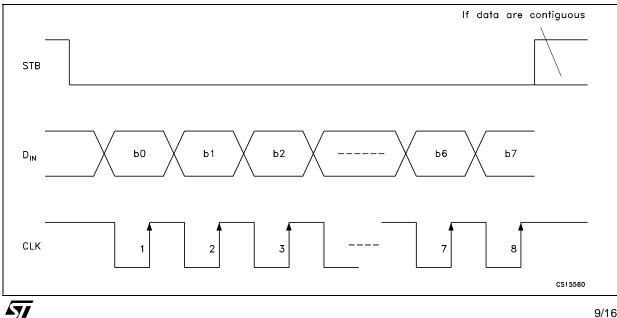


Figure 4: Key Scanning And Display Timing

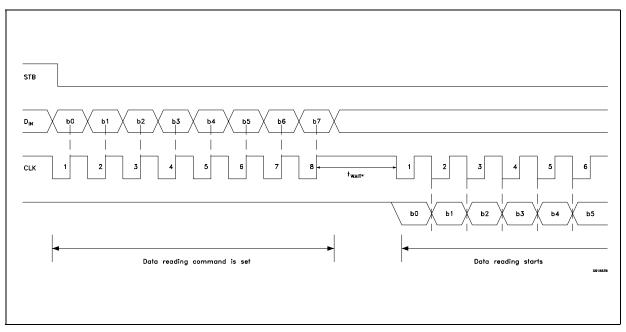
 $^{*}$  The value can be modified by trimmering R<sub>OSC</sub>. One cycle of key scanning consists of one frame, and data of 6 x 4 matrices are stored in RAM.

## SERIAL COMMUNICATION FORMAT





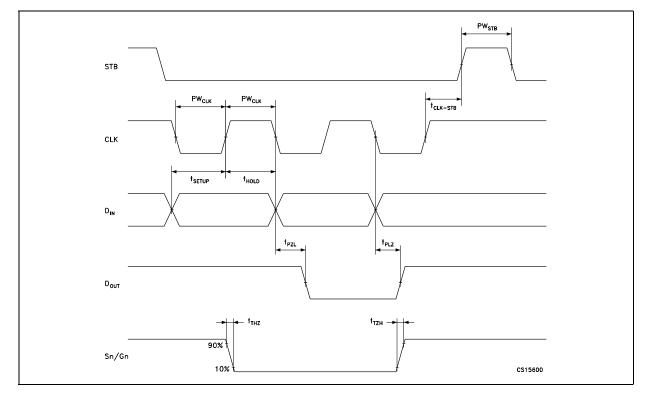
## Figure 6: Transmission (data read)



Because the  $D_{OUT}$  pin is an N-ch open-drain output pin, be sure to connect an external pull-up resistor to this pin (1 k $\Omega$  to 10 k $\Omega$ ).

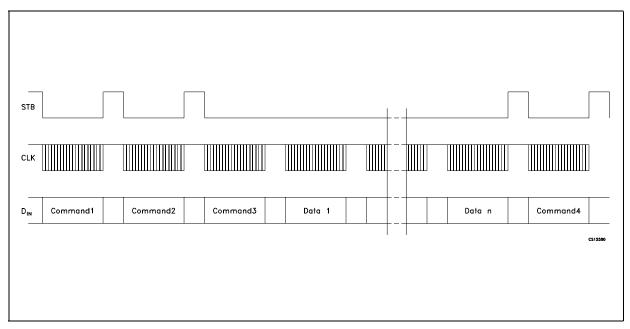
\*: When data are read, a wait time t<sub>WAIT</sub> of 1µs is necessary within the rising edge of the eighth clock that has set the command and the falling one of the first clock that has read the data.

Figure 7: Switching Characteristics Waveform



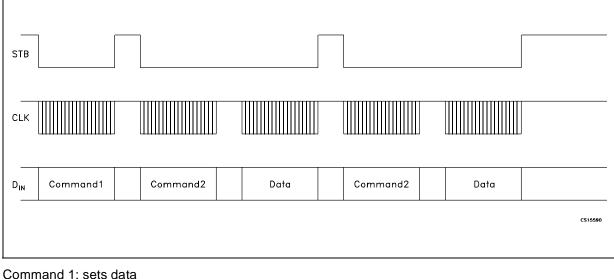
## APPLICATION

## Figure 8: Updating display memory by incrementing address



Command 1: sets display mode Command 2: sets data Command 3: sets address Data 1 to n: transfers display data (22 bytes max.) Command 4: controls display

## Figure 9: Updating specific address

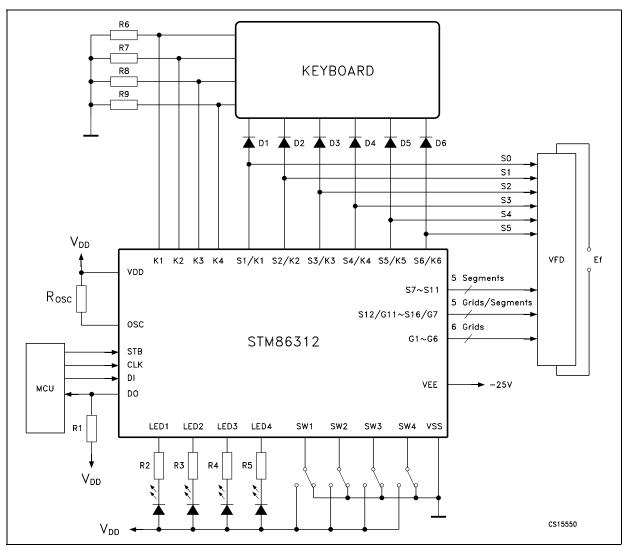


Command 1: sets data Command 2: sets address Data: display data

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# Figure 10: Application Circuit



Note:  $R_{OSC} = 47 k\Omega$  for oscillator resistor R1=1~10 k\Omega for external pull-high resistor R2~R5 = 750 $\Omega$ ~1.2 k $\Omega$ 

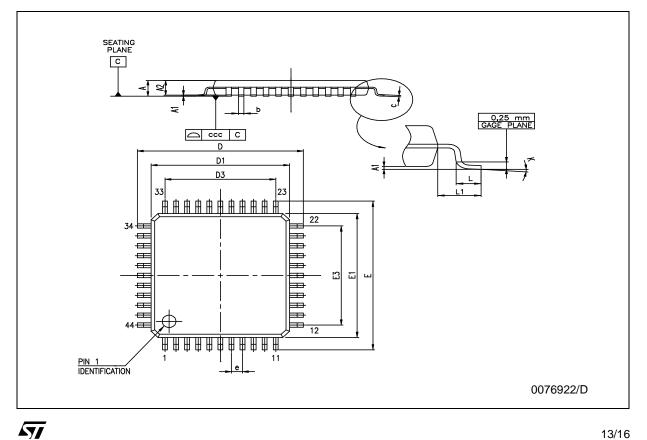
 $R6 \sim R9 = 10 k\Omega$  for external pull-low resistor

D1~D6 = 1N4001

Ef = Filament voltage for VFD.

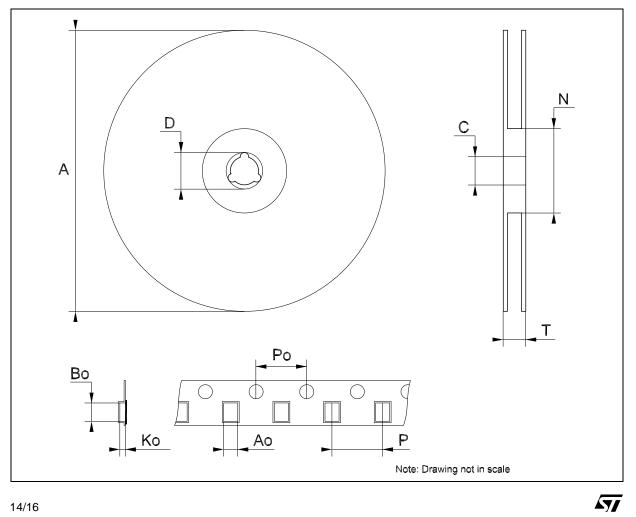
# **PQFP44 MECHANICAL DATA**

DIM.		mm.				
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
А			2.45			0.096
A1			0.25			0.010
A2	1.80	2.00	2.20	0.071	0.079	0.087
b	0.29		0.45	0.011		0.018
С	0.11		0.23	0.004		0.009
D		13.2			0.520	
D1		10.00			0.394	
D3		8.00			0.315	
E		13.2			0.520	
E1		10.00			0.394	
E3		8.00			0.315	
е		0.80			0.031	
L	0.73	0.88	1.03	0.029	0.035	0.041
L1		1.6			0.063	
К	0°	3.5°	7°	0°	3.5°	7°



Tape & Reel PQFP44 MECHANICAL DATA	
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DIM.	mm.			inch		
	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
Ν	60			2.362		
т			30.4			1.196
Ao	12.25		12.45	0482		0.490
Во	12.25		12.45	0482		0.490
Ko	2.1		2.3	0.083		0.091
Po	3.9		4.1	0.153		0.161
Р	15.9		16.1	0.626		0.639



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# Table 8: Revision History

Date	Revision	Description of Changes
27-May-2004	1	First Release

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